DOMAIN STUDIES OF CoCr WITH PERPENDICULAR ANISOTROPY

J.C. Lodder, D. Wind, Th.J.A. Popma, A. Hubert

University of Twente, P.O. Box 217, 7500 AE Enschede, The Netherlands.
University of Erlangen-Nürnberg, Hartenstrasse 7, D-852 Erlangen, FRG.

Abstract. R.F. Magnetron sputtered CoCr films (79/21 at%) with various thicknesses are magnetically characterized. The domain structure is observed by digitally enhanced Kerr microscopy and depends on the Hc/Hk values of the samples. For low and high coercivity films a comparison is made between the measured VSM hysteresis, domain period and a theoretical domain model. The domain shape is a function of the magnetic history of the sample and the blasting created by the deposition process.

INTRODUCTION

The reversal mechanism of magnetization in sputtered CoCr layers for perpendicular recording has still not been completely clarified. Studying the domain configuration can contribute to the solution of this problem.

The magnetic properties of CoCr layers are strongly influenced by variations in microstructure, morphology and chemical homogeneity. Initial layer effects as well as the composition of the columns boundaries and surface are very important for the final behaviour of the domains. The morphology also depends on the sputtering method and parameters used (mainly substrate temperature and Ar gas pressure). From the perpendicular (e.a.) hysteresis loop, measured with the VSM, we have in some cases, observed a typical shoulder which indicated bubble-stripes domains. In order to understand more about the micromagnetics of such layers one has to correlate the morphology, magnetic parameters and domains. Lorentz transmission electron microscopy and digitally enhanced Kerr microscopy have been used for domain observations in CoCr layers. A 1 MeV TEM has to be used for observing CoCr layers thicker than 0.1 μm, up to a maximum of 0.3 μm [1,2]. A specially designed sample stage to exclude a perpendicular lens field from the specimen during domain observations is essential [1,3]. Different domain configurations with in-plane magnetization are observed in thin (≤ 50 nm) CoCr layers [2-4]. This can be explained by variations in the preparation methods and consequently differences in morphology, structure and chemical homogeneity. None of the samples used has a well oriented hcp-axis. For a good textured layer (Co77Cr23), having a thickness of 50 nm, stripe domains with a width of 0.1 μm were observed [2]. A maze domain pattern, known from bubble-like materials, is observed in films of 0.1 μm thickness having a composition of Co82Cr18 [3]. Very thin layers (≤ 30 nm) with in-plane magnetization show the so-called ripple structure in Co89Cr11 [4] and Co79Cr21 [3]. Different domain forms were observed in films with much better orientation and increased thickness (> 0.1 μm) [2-5].

A magnetic black-and-white dot structure with a distance between the dots of the same order as the columnar diameter has been shown by [3]. In this case the film morphology (one column consists of several crystallites) is totally different from the equixed crystal structure present in [2] which shows a stripe domain width in the order of the crystal size. CoCr films in the range between 17-30 at% Cr with a Cr segregation into the column boundaries show dot-like Lorentz images which have the same size as the column diameter [5]. Stripe domain widths (< 0.1 μm) having the same size as the column diameter are also observed in [1]. It was also shown that from relatively thick films (0.3 μm), which are more realistic for recording applications, a channeled-like domain structure as the column size [2] and it is suggested that the domain structure consists of a chain of crystals. Based on neutron depolarization experiments and M.O. measurements of the surface of our CoCr films it can be concluded that the domain width is proportional to Hk, where x is about 0.8 for RF magnetron sputtered films [6-10].

This value is to be tested with the calculated power of 2/3 for a branched domain structure [11] or predicted for the Kittel configuration [12]. It can also be concluded that reversed spike domains can exist and will influence the reversal mode above the critical thickness of magnetron sputtered CoCr layers (500-600 nm) [10]. Unfortunately (spike-) domains cannot be really visualized by neutron depolarization.

EXPERIMENTAL PROCEDURE

The CoCr layers are deposited on Si-substrates by RF magnetron sputtering, having a 3° target, back pressure 1.5X10⁻⁷ mbar and a deposition rate of 6X10⁻⁸ mbar. The film composition is 79 at% Cr and the thickness (h) is determined by XPS. Magnetic measurements are carried out by VSM and torque magnetometer. Substrate material is Si (100) single crystal 10X10 mm². Domains are observed by a digitally enhanced Kerr microscope. The layers are covered with an evaporated 1/4 λ and λ layer. Roughness and banding of the deposited substrate can be measured with the Sloan Dektak 3030 stylus instrument. Column diameter and morphology are determined by STEM observation using a Jeol 200 CX microscope. The relevant sample properties are given in Table I.

<table>
<thead>
<tr>
<th>Sample</th>
<th>Hc/kA/m</th>
<th>h nm</th>
<th>K1/J/m³1/2</th>
<th>Hc/kA/m</th>
<th>Hc/Hk %</th>
<th>Domain shape</th>
</tr>
</thead>
<tbody>
<tr>
<td>1</td>
<td>402</td>
<td>528</td>
<td>8</td>
<td>13.2</td>
<td>525</td>
<td>1.5</td>
</tr>
<tr>
<td>2</td>
<td>418</td>
<td>1230</td>
<td>8</td>
<td>14.3</td>
<td>555</td>
<td>1.4</td>
</tr>
<tr>
<td>4</td>
<td>611</td>
<td>1230</td>
<td>16</td>
<td>14.8</td>
<td>555</td>
<td>3.2</td>
</tr>
<tr>
<td>5</td>
<td>415</td>
<td>1300</td>
<td>24</td>
<td>15.5</td>
<td>595</td>
<td>4.0</td>
</tr>
<tr>
<td>6</td>
<td>413</td>
<td>1220</td>
<td>26</td>
<td>16.0</td>
<td>615</td>
<td>7.5</td>
</tr>
<tr>
<td>7</td>
<td>434</td>
<td>788</td>
<td>60</td>
<td>18.4</td>
<td>675</td>
<td>8.9</td>
</tr>
<tr>
<td>8</td>
<td>426</td>
<td>1436</td>
<td>16</td>
<td>16.4</td>
<td>615</td>
<td>6.5</td>
</tr>
</tbody>
</table>

M.O. KERR OBSERVATIONS

The first Kerr observations on CoCr layers with divergent properties are published in [13]. There a specially designed digitally enhanced Kerr microscope with an image processing system is used. The films have a composition from 17 to 21 at% Cr, thicknesses from 94-622 nm and coercivities from 18-68 kA/m with a sample of 98 kA/m. They all show a more or less stripe-domain structure image close to remanence. It was concluded from this that all samples reversed by domain-wall movement as a continuous medium. Using the same microscope mentioned above, we came to the conclusion with our preliminary results [14] that we have to divide our CoCr layers into 3 categories: namely low Hc (long stripes), medium Hc with short stripes (28<s<48 kA/m) and high coercivity films with a dot-like domain structure. The domain behaviour is clearly connected with the shoulder in the perpendicular hysteresis loop. The Kerr observation method has its limitations in the resolution (≤ 200 nm) and depth of information (± 15 nm). An advantage in relation to transmission Lorentz microscopy is that (surface) magnetic information can be obtained from all thicknesses without any thinning techniques with their consequent disadvantages. A comparison between both observation methods is mentioned in [5]. i.e. the Kerr image of an 0.6 μm thick sample (28 at% Cr) and a Lorentz image of 0.1 μm thick (18 at% Cr) both showing a stripe-like domain pattern. The interpretation of these images is not so simple. The differences in thickness, chemical composition and eventually removal from the original substrate will have an important influence on the domain behaviour. Besides, observation of double layered samples is completely impossible with the Lorentz method. Another advantage of Kerr microscopy is the possibility of applying fields up to 10⁸ kA/m. For most of the CoCr layers the domain process through the whole hysteresis loop can be observed [13,14] within the limitation of the resolving power.
The measured slope is also in good agreement with the calculated line for \( h/\lambda = 25 \) in Fig. 2. For this sample \( \lambda = 38.8 \text{ nm} \), \( \sigma_w = M_n \mu_0 \text{H}_c \mu_0 \text{H}_c^2 = 4.2 \times 10^{-3} \text{ J/m}^2 \), \( \alpha = (1/\text{K}) \). (\( \sigma_w/2 \)) \( = 8.4 \times 10^{-12} \text{ J/m}^2 \) and \( 1 = \sqrt{\text{K}/\text{K}} = 25 \text{ nm} \).

Another low Hc film (#2) has also been measured and calculated. Here we found \( h/\lambda = 55 \) as the best fit. For sample #6 (high Hc) we could not fit both curves (see Figs. 1, 2).

We have also compared the size and shape of the domain period of #2 in the remanent state after saturation with perpendicular DC and demagnetizing fields (Fig. 3).

Fig. 3 Domain configurations of a low coercivity film in remanent (left) and demagnetized (right) state.

At remanent state \( P_{mr} = 918 \text{ mm} \) and after demagnetization \( P_o = 680 \text{ mm} \). This minimum energy position of the stripes results in a very good parallel orientation. Domain observations in the field free state show the magnetic history of the sample. Also different domain configurations can be observed after partial saturation and applying a field under an angle [13]. For a high Hc sample (#6) the dot-like domain shape at demagnetizing field can be roughly given as \( P_o = 665 \text{ mm} \). Typical shoulders in VSM and M.C. Kerr hysteresis loops are not seen in the high Hc films. The calculated model by means of \( P \) and \( T \) is not in good agreement for such films (see Figs. 1, 2).

We have to realize that the method we used makes the following assumptions namely: the domain-wall energy is independent of \( h \), the wall volume is neglected and, last but not least, the coercivity is zero.

Stresses have a lot of influence on the domain configuration. The bending of the samples is measured. A line scan over the total sample length in two orthogonal directions is made. The curvature (e.g. the strain) is not always isotropic over a certain area and can vary from place to place in the same sample. We found that samples have a different bending in the orthogonal directions showing straight stripe domains (see Fig. 4a). More or less meandered domains are seen in Fig. 4b which is made from a position with equal bending in two directions.

Fig. 4 Domains of #2 at \( H_o = 260 \text{ Oe} \) as a function of the bending in two orthogonal directions (xy).

At the moment we have the impression that stress in our magnetron sputtered films is higher than in our RF sputtered ones [4]. Consequently the stress will have to be studied in more detail in relation to the total anisotropy factor in the films.

MORPHOLOGY

Cross-sections were studied with the STEM mode of the electron microscope. The fractional surfaces were prepared by cooling the samples in liquid N\(_2\) before breaking them, to obtain a brittle fracture. The columnar-like morphology can be clearly seen in all our films independent of the Hc/Hk value.
For samples #3, 5 and 8 respectively an average column size D (measured at the surface) of 40, 45 and 70 nm is determined. Consequently Pmc/D values are 26, 21 and 12. From another low (82) and high (86) coercivity film we have measured Pmc (see above) and using these values we come to the conclusion that the coercivity consists of 4-8 columns, for these films.

We also have to realize that the columns are a function of the layer thickness. Studying the fractional surfaces it can be seen that the three films show a typical fractured plane close to the substrate. This is interpreted as belonging to the initial layer which is also seen in the in-plane VSM graphs of the same samples.

**COERCIVITY**

The coercivity in ferromagnetic layers with perpendicular anisotropy is determined by two factors:

1. The type of magnetization process involved i.e. is the magnetization reversing by (coherent) rotation or by domain-wall movement?

2. Morphology of the layer i.e. shape and dimensions of the crystallites (columns), nature of the boundaries, surface and initial layer properties.

In fact these two factors are strongly interrelated and their properties are strongly influenced by the deposition parameters such as temperature, Ar etc. Based on general knowledge about ferromagnetic films we can conclude that the presence of stripe domains in CoCr must be quite common because the layer splits up into such a configuration by reducing its demagnetizing energy. Theoretical support for reversed domains in uniaxial thin layers with perpendicular anisotropy is provided by [11,16]. From research on permanent magnets, supporting arguments for the relation coercivity and reversal mechanism are given by [17]. In polycrystalline and/or columnar-like materials the critical domain size is difficult to estimate because it is influenced by the presence of neighbouring particles and their interactions. If the magnetization reversal takes place by coherent rotation Hc must be equal to the HK. In our case all the layers have Hc(8K). An explanation for this effect can be made by introducing the so-called fanning, curling and buckling modes. These can in principle, only occur in layers in which the magnetic anisotropy is mainly produced by shape anisotropy. In CoCr the main anisotropy is configurated by magneto crystalline anisotropy. On the other hand experimental work on high coercivity Co or Co-P layers [18-20] shows domain structures independent of the source of the magnetic anisotropy. The presence of a domain structure and the results of other measurements like hysteresis losses and Hc vs. angle are not completely in line. This could probably be explained by the presence of interaction domains which were first introduced by [21]. Here particle exchange forces are negligible and the magnetic moments are mutually aligned by magnetoelastic interactions [22]. Recently this model was mentioned as a possible mechanism in CoCr layers [23]. For low Hc the nucleation density is much lower than for high Hc ones. It is clearly shown that nuclel stripe out at the tips of the domain after decreasing the applied field [11,14]. The observable sizes of the dots (coming from saturation) in high Hc films is determined by the resolving power of the Kerr microscope. Nevertheless these dots do not expand very much due to the very close surrounding of neighbouring dots. The reversal in one column could be, depending on its dimensions, initiated by a reversed domain. These small sizes cannot be resolved by Kerr microscopy and it can be accepted that such domains are no longer present in thinned TEM specimens. The particle behavior without exchange coupling is suggested by Cr segregation at the column boundaries. At the moment only preliminary results are available from Scanning Auger Microspectroscopy (SAM) and wet chemical etch procedures. From the latter we found only qualitatively a higher Cr content at the surface than in the bulk of all our samples. From a SAM measurement of a factional surface of a high coercivity film we came the conclusion that there is a Cr segregation at the column boundaries.

**REFERENCES**


**CONCLUSIONS**

Different domain configurations can be expected as a function of the coercivity. Factors like stress and magnetic history play an important role. For low Hc material the stripe domain theory is in good agreement with the measured P values from Kerr observations and the hysteresis loop. One remanent domain (dot, stripe) of all our films consists of several columns. A direct correlation between the type of domains and some aspects of the macroscopic hysteresis loop (Hc, shoulder) can be made (see also [14, 24]).

Stress plays an important role in the domain behaviour.